

Phase Control Thyristors (Hockey PUK Version), 350 A



TO-200AB (A-PUK)

PRODUCT SUMMARY						
Package	TO-200AB (A-PUK)					
Diode variation	Single SCR					
I _{T(AV)}	350 A					
V _{DRM} /V _{RRM}	400 V to 2000 V					
V_{TM}	1.96 V					
I _{GT}	150 mA					
TJ	-40 °C to 125 °C					

FEATURES

- · Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AB (A-PUK)



- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		350	A		
I _{T(AV)}	T _{hs}	55	°C		
1		660	А		
I _{T(RMS)}	T _{hs}	25	°C		
I _{TSM}	50 Hz	5000	А А		
	60 Hz	5230			
I ² t	50 Hz	125	kA ² s		
1-1	60 Hz	114			
V _{DRM} /V _{RRM}		400 to 2000	V		
tq	Typical	100	μs		
TJ		-40 to 125	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$\begin{aligned} & I_{DRM}/I_{RRM} \text{ MAXIMUM} \\ & \text{AT T}_{J} = T_{J} \text{ MAXIMUM} \\ & \text{mA} \end{aligned}$				
	04	400	500					
	08	800	900					
VS-ST180CC	12	1200	1300	30				
V3-31160CC	16	1600	1700	30				
	18	1800	1900					
	20	2000	2100					



ABSOLUTE MAXIMUM RATINGS	3							
PARAMETER	SYMBOL		VALUES	UNITS				
Maximum average on-state current	1	180° condu	180° conduction, half sine wave			Α		
at heatsink temperature	I _{T(AV)}	double side	(single side) co	oled	55 (85)	°C		
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	heatsink tempe	erature double side cooled	660			
		t = 10 ms	No voltage		5000			
Maximum peak, one-cycle		t = 8.3 ms	reapplied		5230	A kA ² s		
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}	Sinusoidal half wave, initial $T_J = T_J$ maximum	4200			
		t = 8.3 ms	reapplied		4400			
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage reapplied		125			
		t = 8.3 ms			114			
		t = 10 ms			88			
		t = 8.3 ms	reapplied		81			
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied			1250	kA²√s		
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$), $T_J = T_J$ maximum	1.08	V		
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			V		
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum			1.18	mΩ		
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			1.14	11152		
Maximum on-state voltage	V_{TM}	$I_{pk} = 750 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			1.96	V		
Maximum holding current	I _H	T 05:00 and a set 40 V and the b		T 0500 1 140V 111 1	T 05 00 and a 140 1/2 in	T 05.00	600	mΛ
Maximum (typical) latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load			1000 (300)	mA		

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/μs		
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}$, $T_J = 25 °C$	1.0	5		
Typical turn-off time	t _q	$\begin{aligned} I_{TM} &= 300 \text{ A, } T_J = T_J \text{ maximum, dI/dt} = 20 \text{ A/}\mu\text{s,} \\ V_R &= 50 \text{ V, dV/dt} = 20 \text{ V/}\mu\text{s, gate 0 V 100 }\Omega, t_p = 500 \mu\text{s} \end{aligned}$	100	μs		

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNIT S		
Maximum critical rate of rise of off-state voltage	dV/dt	T _J = T _J maximum linear to 80 % rated V _{DRM}	500	V/µs		
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	30	mA		



TRIGGERING								
PARAMETER	SYMBOL	-	TEST CONDITIONS			UNIT		
PANAMETEN	STWIBOL	'	EST CONDITIONS	typ.	max.	S		
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	1	0	W		
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV		
Maximum peak positive gate current	I _{GM}			3	.0	Α		
Maximum peak positive gate voltage	+ V _{GM}	$T_J = T_J$ maximum, $t_p \le 5$ ms			$T_J = T_J$ maximum, $t_p \le 5$ ms		.0	V
Maximum peak negative gate voltage	- V _{GM}				.0	v		
DC gate current required to trigger	I _{GT}	T _J = - 40 °C		180	-			
		T _J = 25 °C		90	150	mA		
		T _J = 125 °C	Maximum required gate trigger/ current/voltage are the lowest value	40	-			
		T _J = - 40 °C	which will trigger all units 12 V	2.9	-			
DC gate voltage required to trigger	V _{GT}	T _J = 25 °C	anode to cathode applied	1.8	3.0	٧		
		T _J = 125 °C		1.2	-			
DC gate current not to trigger	I _{GD}	T. T. magazina	Maximum gate current/voltage not to trigger is the maximum value	1	0	mA		
DC gate voltage not to trigger	V _{GD}	$T_J = T_J \text{ maximum}$	which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.	25	V		

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER SYMBOL		TEST CONDITIONS	VALUES	UNIT S		
Maximum operating junction temperature range	T _J		-40 to 125	°C		
Maximum storage temperature range Ts			-40 to 150			
Maximum thermal resistance, junction to heatsink	R _{thJ-hs}	DC operation single side cooled	0.17			
		DC operation double side cooled	0.08	k/W		
Maximum thermal resistance,	R _{thC-hs}	DC operation single side cooled	0.033	N/VV		
case to heatsink		DC operation double side cooled	0.017			
Mounting force, ± 10 %			4900 (500)	N (kg)		
Approximate weight			50	g		
Case style		See dimensions - link at the end of datasheet		A-PUK)		



△R _{thJC} CONDUCTION								
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS		
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE				
180°	0.015	0.015	0.011	0.011				
120°	0.018	0.019	0.019	0.019				
90°	0.024	0.024	0.026	0.026	$T_J = T_J$ maximum	K/W		
60°	0.035	0.035	0.036	0.037				
30°	0.060	0.060	0.060	0.061				

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Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

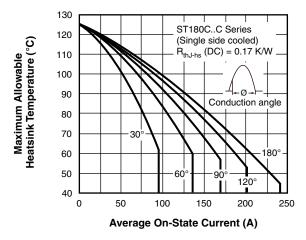


Fig. 1 - Current Ratings Characteristics

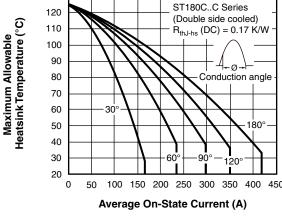


Fig. 3 - Current Ratings Characteristics

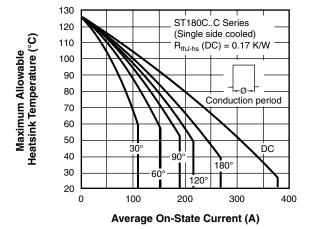


Fig. 2 - Current Ratings Characteristics

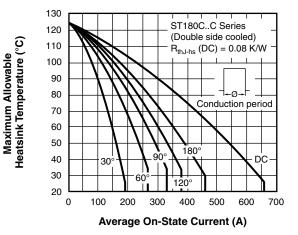


Fig. 4 - Current Ratings Characteristics

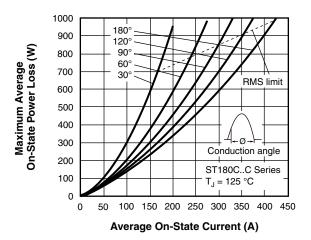


Fig. 5 - On-State Power Loss Characteristics

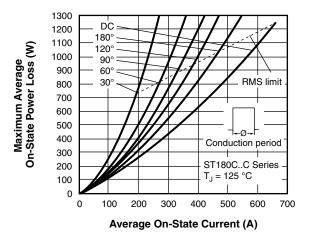
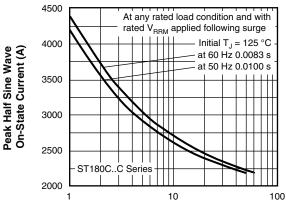


Fig. 6 - On-State Power Loss Characteristics



Number of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

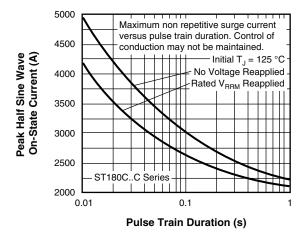


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

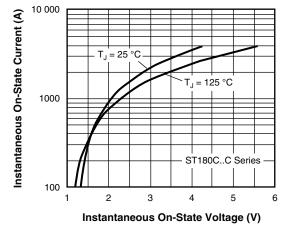


Fig. 9 - On-State Voltage Drop Characteristics

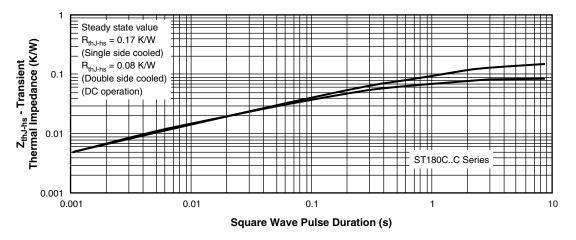


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

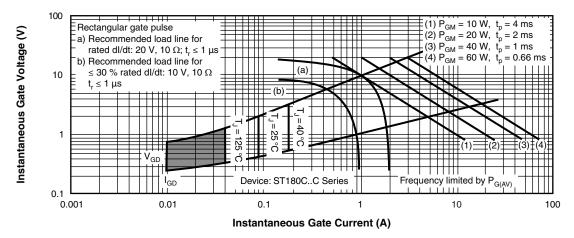
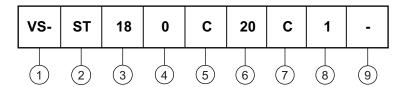


Fig. 11 - Gate Characteristics



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Thyristor

Essential part number

0 = Converter grade

5 - C = Ceramic PUK

6 - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

7 - C = PUK case TO-200AB (A-PUK)

- 0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads)

1 = Fast-on terminals (gate and auxiliary cathode unsoldered leads)

2 = Eyelet terminals (gate and auxiliary cathode soldered leads)

3 = Fast-on terminals (gate and auxiliary cathode soldered leads)

9 - Critical dV/dt: • None = 500 V/µs (standard selection)

L = 1000 V/μs (special selection)

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95074			

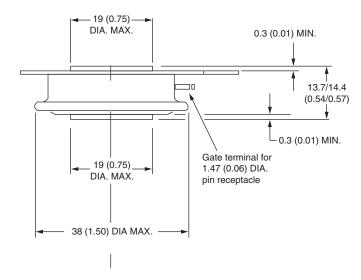


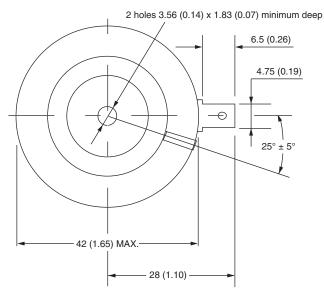
TO-200AB (A-PUK)

DIMENSIONS in millimeters (inches)

Anode to gate

Creepage distance: 7.62 (0.30) minimum Strike distance: 7.12 (0.28) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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